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September 1983 Revised May 2005

MM74HC373 3-STATE Octal D-Type Latch

General Description

The MM74HC373 high speed octal D-type latches utilize advanced silicon-gate CMOS technology. They possess the high noise immunity and low power consumption of standard CMOS integrated circuits, as well as the ability to drive 15 LS-TTL loads. Due to the large output drive capability and the 3-STATE feature, these devices are ideally suited for interfacing with bus lines in a bus organized sys-

When the LATCH ENABLE input is HIGH, the Q outputs will follow the D inputs. When the LATCH ENABLE goes LOW, data at the D inputs will be retained at the outputs until LATCH ENABLE returns HIGH again. When a high logic level is applied to the OUTPUT CONTROL input, all outputs go to a high impedance state, regardless of what signals are present at the other inputs and the state of the storage elements.

The 74HC logic family is speed, function, and pin-out compatible with the standard 74LS logic family. All inputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

Features

- Typical propagation delay: 18 ns
- Wide operating voltage range: 2 to 6 volts
- Low input current: 1 µA maximum
- Low quiescent current: 80 µA maximum (74 Series)
- Output drive capability: 15 LS-TTL loads

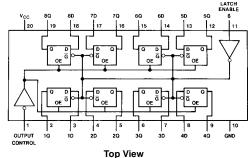
Ordering Code:

Order Number	Package Number	Package Description
MM74HC373WM	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
MM74HC373SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
MM74HC373MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
MM74HC373N	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Connection Diagram

Pin Assignments for DIP, SOIC, SOP and TSSOP



Truth Table

	Output	Latch	Data	373
	Control	Enable		Output
Γ	L	Н	Н	Н
	L	Н	L	L
	L	L	X	Q_0
	Н	X	X	Z

- $\mathbf{Q}_0 = \mathbf{Level}$ of output before steady-state input conditions were established. $\mathbf{Z} = \mathbf{High}$ Impedance

Absolute Maximum Ratings(Note 1)

(Note 2)

Supply Voltage (V _{CC})	-0.5 to +7.0V
DC Input Voltage (V _{IN})	-1.5 to V_{CC} +1.5V
DC Output Voltage (V _{OUT})	-0.5 to V_{CC} $+0.5V$
Clamp Diode Current (I _{IK} , I _{OK})	±20 mA
DC Output Current, per pin (I _{OUT})	±35 mA
DC V _{CC} or GND Current, per pin (I _{CC})	±70 mA
Storage Temperature Range (T _{STG})	-65°C to +150°C
Power Dissipation (P _D)	
(Note 3)	600 mW
S.O. Package only	500 mW
Lead Temperature (T _L)	
(Soldering 10 seconds)	260°C

Recommended Operating Conditions

	Min	Max	Units
Supply Voltage (V _{CC})	2	6	V
DC Input or Output Voltage			
(V_{IN}, V_{OUT})	0	V_{CC}	V
Operating Temperature Range (T _A)	-40	+85	°C
Input Rise or Fall Times			
$(t_r, t_f) V_{CC} = 2.0V$		1000	ns
V _{CC} = 4.5V		500	ns
$V_{CC} = 6.0V$		400	ns

Note 1: Absolute Maximum Ratings are those values beyond which damage to the device may occur.

Note 2: Unless otherwise specified all voltages are referenced to ground.

Note 3: Power Dissipation temperature derating — plastic "N" package: –
12 mW/°C from 65°C to 85°C.

DC Electrical Characteristics

Symbol	Parameter	Conditions	v _{cc}	T _A = 25°C		$T_A = -40 \text{ to } 85^{\circ}C$ $T_A = -55 \text{ to}$		25°C Units
Syllibol		Conditions		Тур		Guaranteed L	imits	Units
V _{IH}	Minimum HIGH Level		2.0V		1.5	1.5	1.5	V
	Input Voltage		4.5V		3.15	3.15	3.15	V
			6.0V		4.2	4.2	4.2	V
V _{IL}	Maximum LOW Level		2.0V		0.5	0.5	0.5	٧
	Input Voltage		4.5V		1.35	1.35	1.35	V
			6.0V		1.8	1.8	1.8	V
V _{OH}	Minimum HIGH Level	$V_{IN} = V_{IH}$ or V_{IL}						
	Output Voltage	$ I_{OUT} \leq 20~\mu A$	2.0V	2.0	1.9	1.9	1.9	V
			4.5V	4.5	4.4	4.4	4.4	V
			6.0V	6.0	5.9	5.9	5.9	V
		$V_{IN} = V_{IH}$ or V_{IL}						
		$ I_{OUT} \le 6.0 \text{ mA}$	4.5V	4.2	3.98	3.84	3.7	V
		$ I_{OUT} \le 7.8 \text{ mA}$	6.0V	5.7	5.48	5.34	5.2	V
V _{OL}	Maximum LOW Level	$V_{IN} = V_{IH}$ or V_{IL}						
	Output Voltage	$ I_{OUT} \le 20 \mu A$	2.0V	0	0.1	0.1	0.1	V
			4.5V	0	0.1	0.1	0.1	V
			6.0V	0	0.1	0.1	0.1	V
		$V_{IN} = V_{IH}$ or V_{IL}						
		$ I_{OUT} \le 6.0 \text{ mA}$	4.5V	0.2	0.26	0.33	0.4	V
		$ I_{OUT} \le 7.8 \text{ mA}$	6.0V	0.2	0.26	0.33	0.4	V
I _{IN}	Maximum Input	$V_{IN} = V_{CC}$ or GND	6.0V		±0.1	±1.0	±1.0	μА
	Current							
loz	Maximum 3-STATE	$V_{IN} = V_{IH}$ or V_{IL} , $OC = V_{IH}$	6.0V		±0.5	±5	±10	μА
	Output Leakage	$V_{OUT} = V_{CC}$ or GND						
	Current							
I _{CC}	Maximum Quiescent	V _{IN} = V _{CC} or GND	6.0V		8.0	80	160	μА
	Supply Current	I _{OUT} = 0 μA						

Note 4: For a power supply of 5V \pm 10% the worst case output voltages (V_{OH}, and V_{OL}) occur for HC at 4.5V. Thus the 4.5V values should be used when designing with this supply. Worst case V_{IH} and V_{IL} occur at V_{CC} = 5.5V and 4.5V respectively. (The V_{IH} value at 5.5V is 3.85V.) The worst case leakage current (I_{IN}, I_{CC}, and I_{OZ}) occur for CMOS at the higher voltage and so the 6.0V values should be used.

AC Electrical Characteristics

 $V_{CC} = 5V$, $T_A = 25^{\circ}C$, $t_r = t_f = 6$ ns

Symbol	Parameter	Conditions	Тур	Guaranteed	Units
				Limit	
t_{PHL} , t_{PLH}	Maximum Propagation Delay, Data to Q	C _L = 45 pF	18	25	ns
t _{PHL} , t _{PLH}	Maximum Propagation Delay, LE to Q	C _L = 45 pF	21	30	ns
t_{PZH}, t_{PZL}	Maximum Output Enable Time	$R_L = 1 k\Omega$	20	28	ns
		C _L = 45 pF			
t _{PHZ} , t _{PLZ}	Maximum Output Disable Time	$R_L = 1 \text{ k}\Omega$	18	25	ns
		$C_L = 5 pF$			
t _S	Minimum Set Up Time			5	ns
t _H	Minimum Hold Time			10	ns
t _W	Minimum Pulse Width		9	16	ns

AC Electrical Characteristics

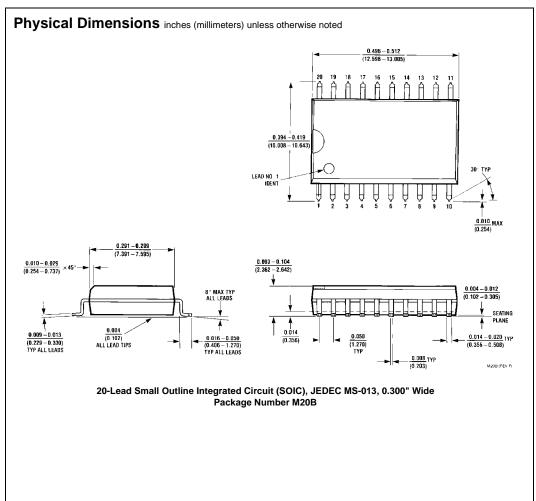
 $V_{CC} = 2.0-6.0V$, $C_L = 50$ pF, $t_f = t_f = 6$ ns (unless otherwise specified)

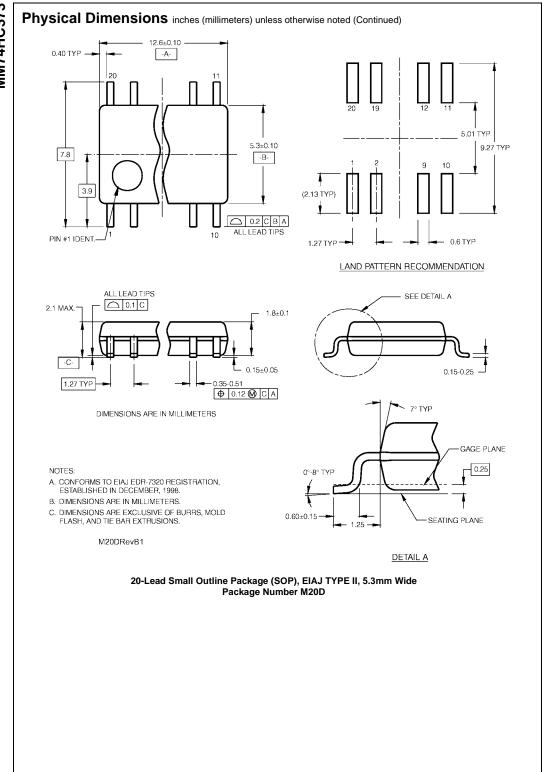
Symbol	Parameter	Conditions	v _{cc}	T _A = 25°C		$T_A = -40 \text{ to } 85^{\circ}\text{C}$ $T_A = -55 \text{ to } 125^{\circ}\text{C}$		
Cymbol			•66	Тур		Guaranteed L	imits	Units
t _{PHL} , t _{PLH}	Maximum Propagation	C _L = 50 pF	2.0V	50	150	188	225	ns
	Delay, Data to Q	$C_L = 150 pF$	2.0V	80	200	250	300	ns
		C _L = 50 pF	4.5V	22	30	37	45	ns
		C _L = 150 pF	4.5V	30	40	50	60	ns
		C _L = 50 pF	6.0V	19	26	31	39	ns
		C _L = 150 pF	6.0V	26	35	44	53	ns
t _{PHL} , t _{PLH}	Maximum Propagation	C _L = 50 pF	2.0V	63	175	220	263	ns
	Delay, LE to Q	C _L = 150 pF	2.0V	110	225	280	338	ns
		C _L = 50 pF	4.5V	25	35	44	52	ns
		C _L = 150 pF	4.5V	35	45	56	68	ns
		C _L = 50 pF	6.0V	21	30	37	45	ns
		C _L = 150 pF	6.0V	28	39	49	59	ns
t _{PZH} , t _{PZL}	Maximum Output	$R_L = 1 k\Omega$						
	Enable Time	C _L = 50 pF	2.0V	50	150	188	225	ns
		C _L = 150 pF	2.0V	80	200	250	300	ns
		C _L = 50 pF	4.5V	21	30	37	45	ns
		C _L = 150 pF	4.5V	30	40	50	60	ns
		C _L = 50 pF	6.0V	19	26	31	39	ns
		C _L = 150 pF	6.0V	26	35	44	53	ns
t _{PHZ} , t _{PLZ}	Maximum Output Disable	$R_L = 1 k\Omega$	2.0V	50	150	188	225	ns
	Disable Time	C _L = 50 pF	4.5V	21	30	37	45	ns
			6.0V	19	26	31	39	ns
t _S	Minimum Set Up Time		2.0V		50	60	75	ns
			4.5V		9	13	15	ns
			6.0V		9	11	13	ns
t _H	Minimum Hold Time		2.0V		5	5	5	ns
			4.5V		5	5	5	ns
			6.0V		5	5	5	ns
t _W	Minimum Pulse Width		2.0V	30	80	100	120	ns
			4.5V	10	16	20	24	ns
			6.0V	9	14	18	20	ns
t _{THL} , t _{TLH}	Maximum Output Rise	C _L = 50 pF	2.0V	25	60	75	90	ns
	and Fall Time		4.5V	7	12	15	18	ns
			6.0V	6	10	13	15	ns
C _{PD}	Power Dissipation	(per latch)						
=	Capacitance (Note 5)	OC = V _{CC}		30				pF
		OC = GND		50				pF
C _{IN}	Maximum Input Capacitance			5	10	10	10	pF

AC Electrical Characteristics (Continued)

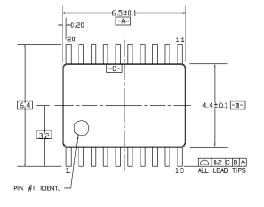
Symbol	Parameter	Conditions	v _{cc}	T _A = 25°C		T _A = -40 to 85°C T _A = -55 to 125°C		Units
- J	. a.a.noto			Тур		Guaranteed L	imits	- 011110
C _{OUT}	Maximum Output			15	20	20	20	pF
	Capacitance							

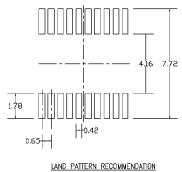
Note 5: C_{PD} determines the no load dynamic power consumption, $P_D = C_{PD} \ V_{CC}^2 \ f + I_{CC} \ V_{CC}$, and the no load dynamic current consumption, $I_S = C_{PD} \ V_{CC} \ f + I_{CC}$.



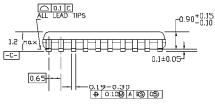


$\textbf{Physical Dimensions} \ \ \text{inches (millimeters) unless otherwise noted (Continued)}$





0.09-0.20



DIMENSIONS ARE IN MILLIMETERS

| U.I.UM | A | RS | US |

NOTES:

- A. CONFORMS TO JEDEC REGISTRATION MD-153, VARIATION AC, REF NOTE 6, DATE 7/93.
- B. DIMENSIONS ARE IN MILLIMETERS.
- C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLDS FLASH, AND TIE BAR EXTRUSIONS.
- D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

R0.09min GAGE PLANE - 8*7 -0.6±0.1-0.09min GAGE PLANE - 8.7 -0.09min R0.09min

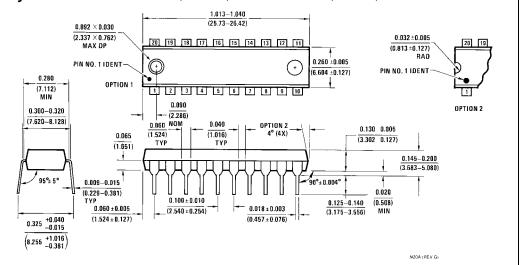
SEE DETAIL A

DETAIL A

MTC20REVD1

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide Package Number MTC20

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide Package Number N20A

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